

Non radiative energy transfer mediated high efficiency radial p-n junction hybrid solar cells using nanocrystalline Si quantum dots and Si nanowires

By

Mrinal Dutta

International Center for Materials

Nanoarchitectonics (MANA),

National Institute for Materials Science,

Tsukuba, Japan

Background

1. **Purcell** (1946): Vacuum photon field induced emission from an excited molecule can be manipulated by changing field around it.



Unverified till 1960

2. **Forster**: Direct dipole-dipole interaction between molecules can transfer energy from one molecule to another



Verified by many researchers in bio-imaging and other fields

3. **Drexhage** (1960): Radiative decay rate of an emitting molecule near metal surface

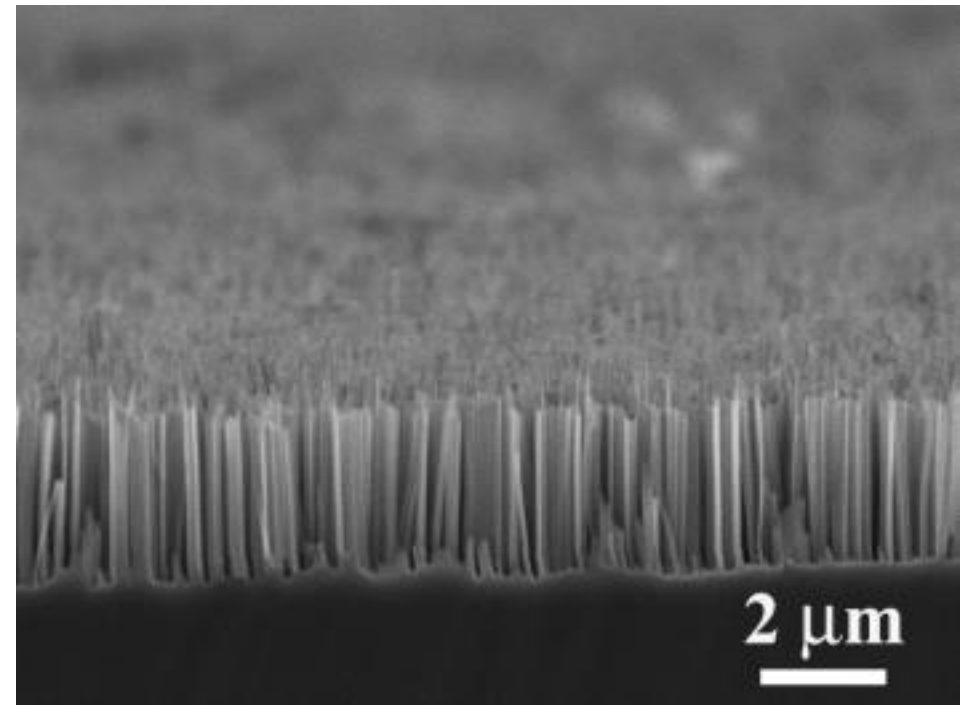
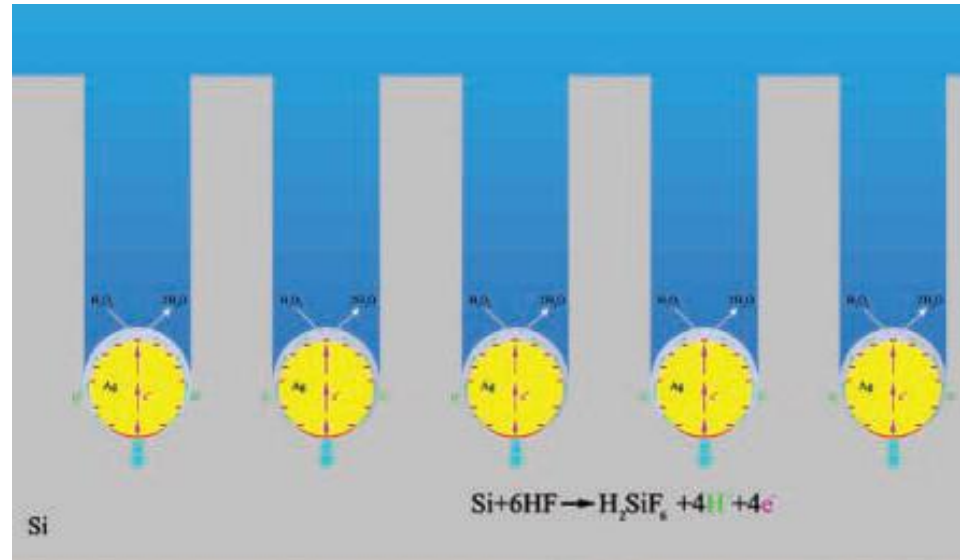
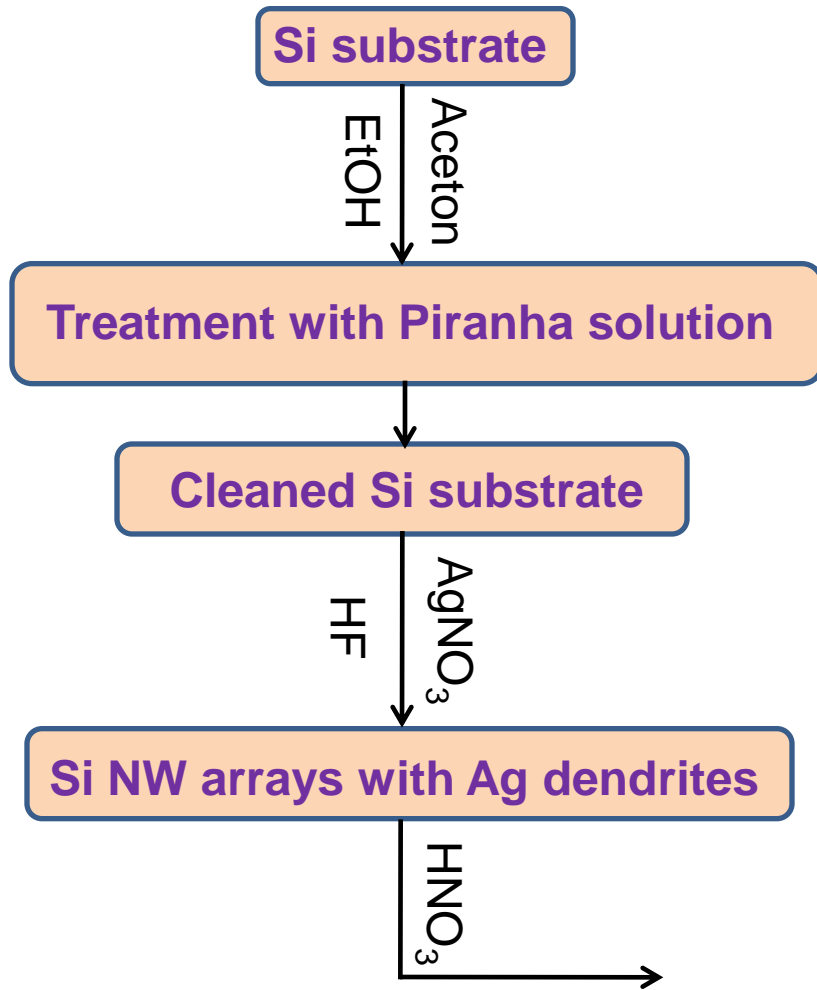


Semiconductor cavity quantum electrodynamics
Photophysics of molecules as a function of the distance

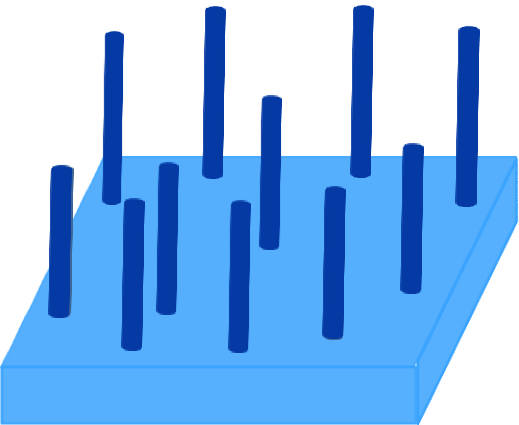
4. **Dexter** (1985): Proposed quantum mechanical theory of the energy transfer from an excited molecule to underlying direct or indirect band gap semiconductor

❑ Very recently, nonradiative energy transfer (NRET) has been proposed for hybrid nanostructures that combine absorbing components (e.g., quantumdots) with high-mobility semiconducting channels.

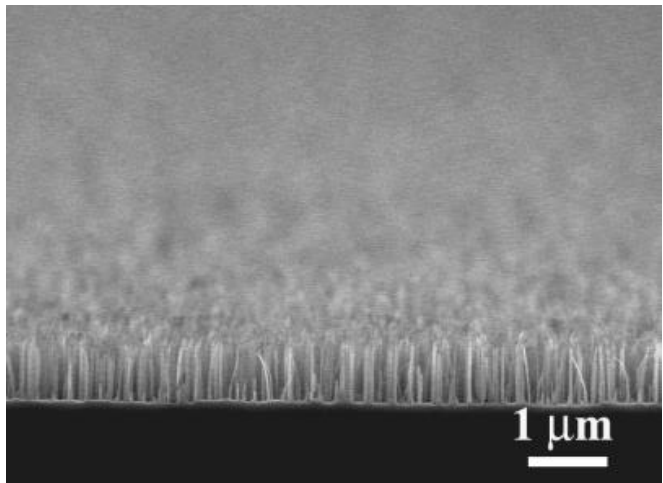
Metal-catalyzed electroless etching (MCEE)



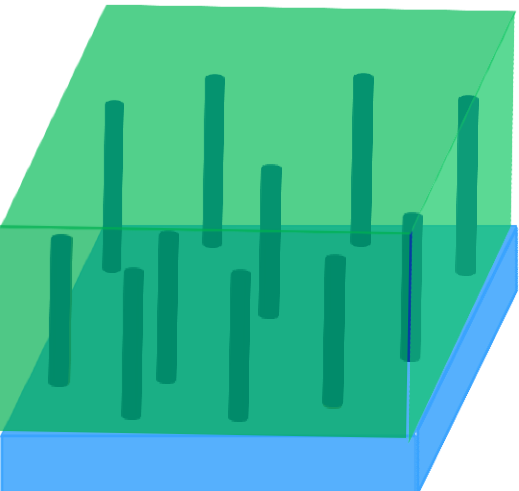
Growth of radial junction: CVD deposition



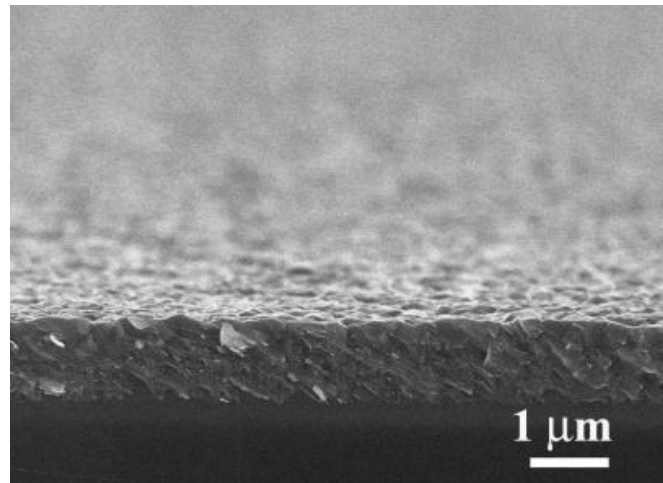
n-type Si nanowires



↓
CVD



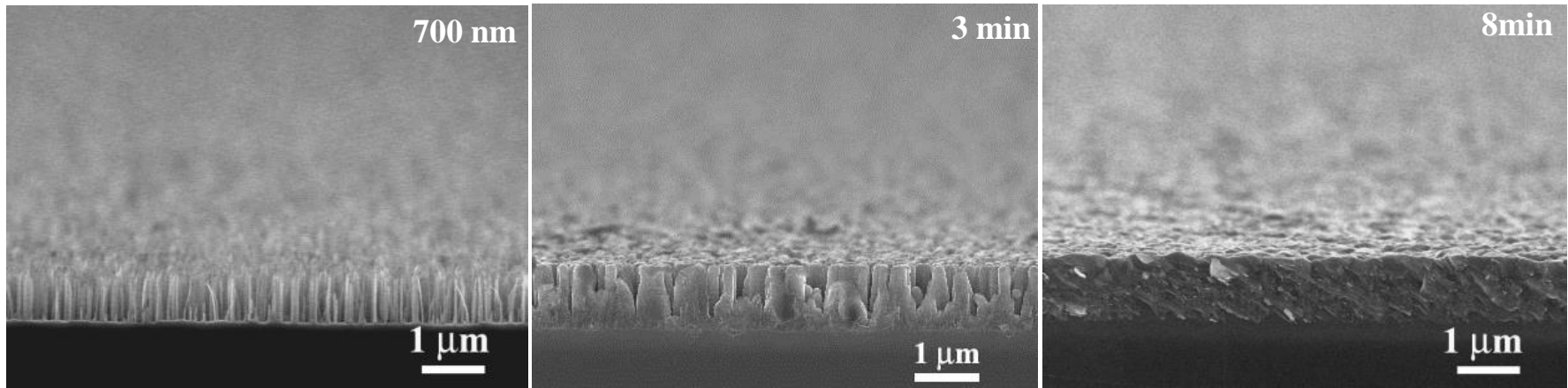
p-n radial junction



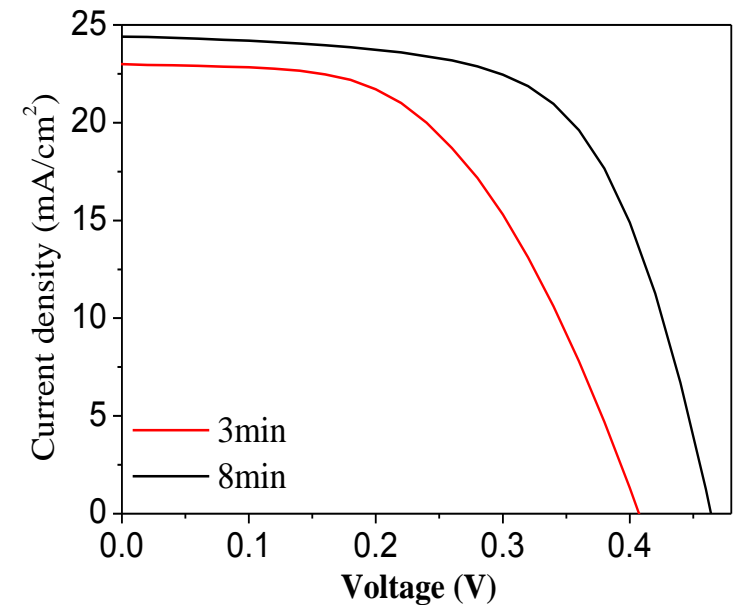
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CVD



p-n Core shell structure vs. n-SiNWs embedded in p-Si matrix structure

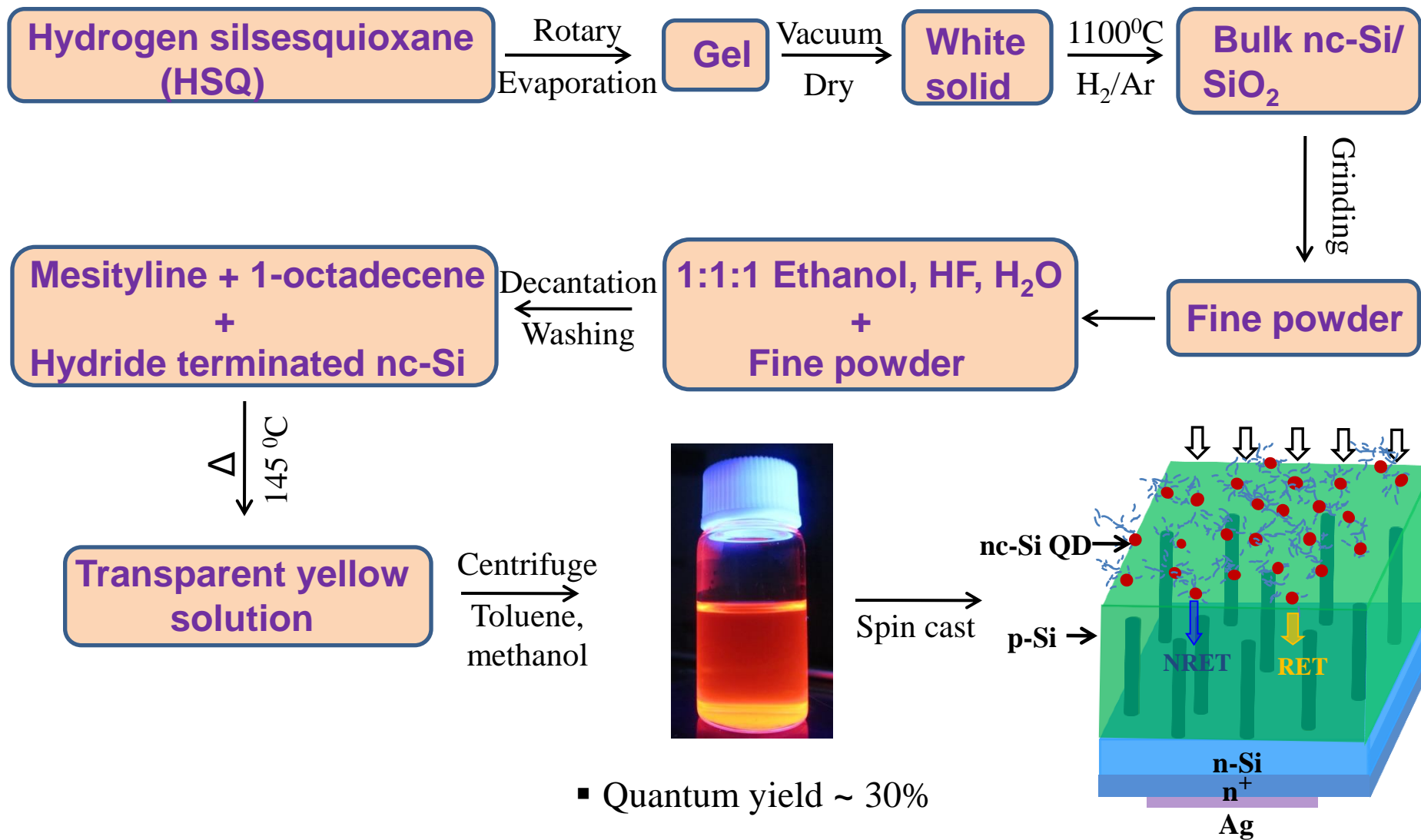


sample	V_{oc} (V)	J_{sc} (mA/cm ²)	FF	η (%)	R_s (Ω /cm ²)
n-Si NW arrays embedded in p-Si	0.46	24.4	0.63	7	2.4
Core-shell structure	0.41	23	0.5	4.71	4.6

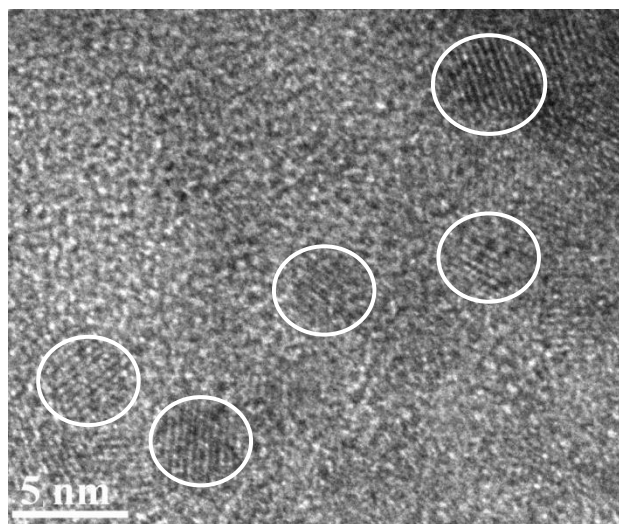


- Al ~ 100 nm
- Ag ~ 100 nm

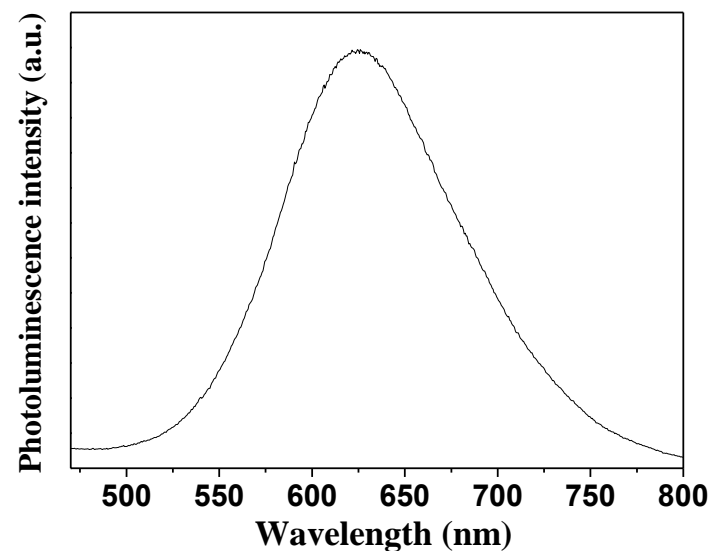
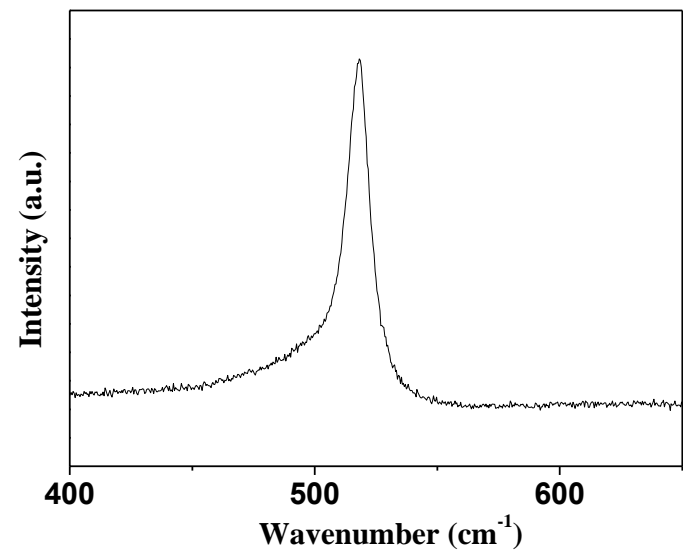
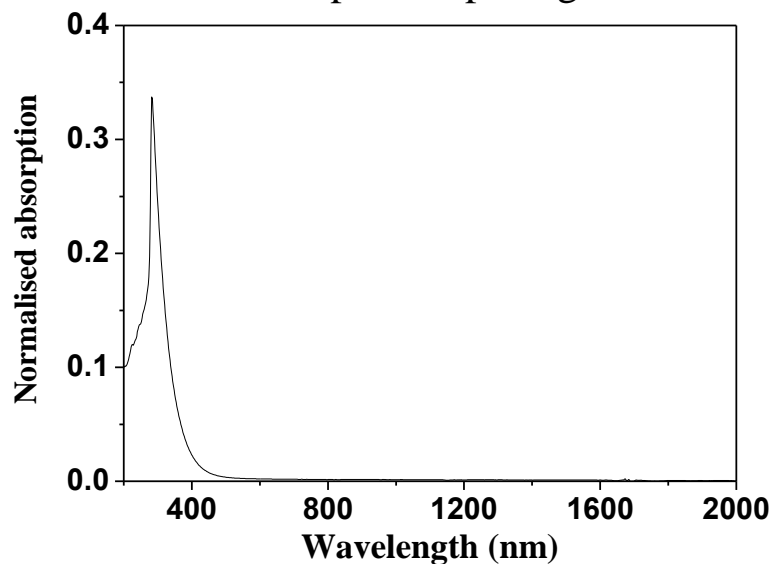
Synthesis of colloidal nc-Si QDs and hybrid cells



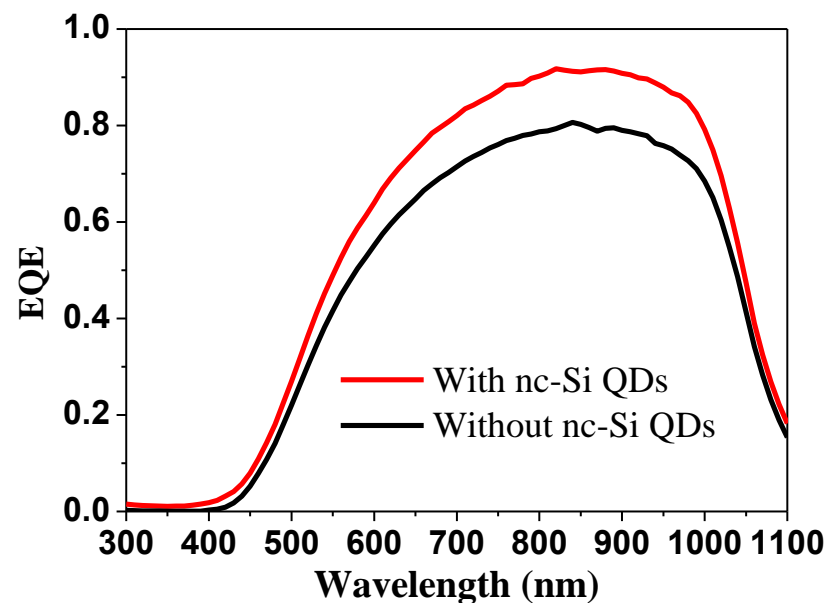
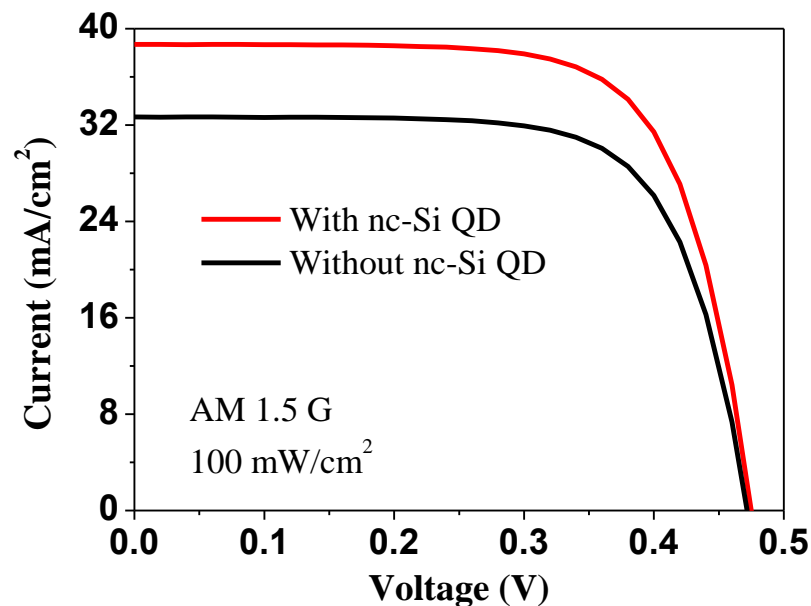
Morphological and spectroscopic characterisations of nc-Si QDs



- Average diameter ~ 3.7 nm
- lattice interplanar spacing of 0.31 nm

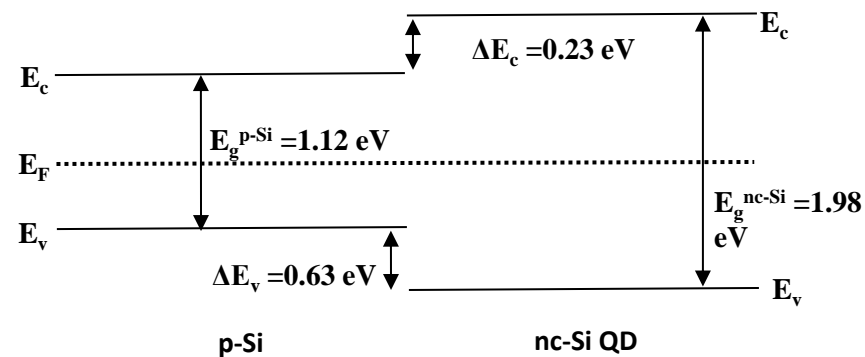
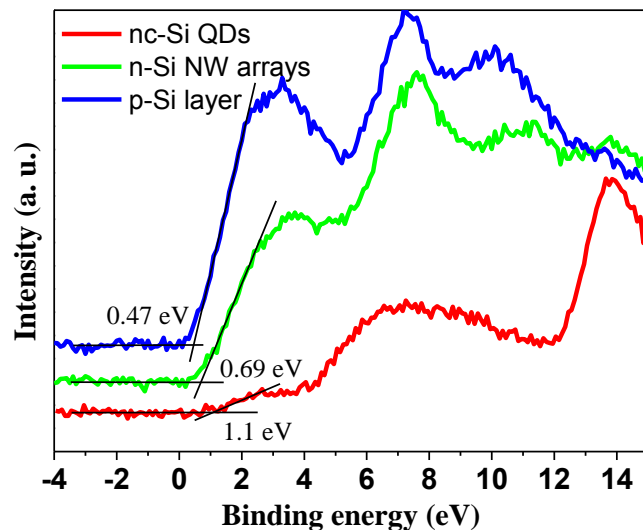
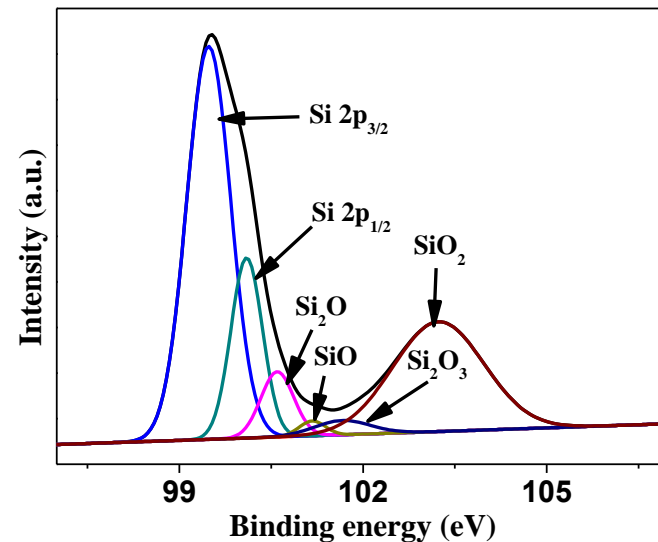
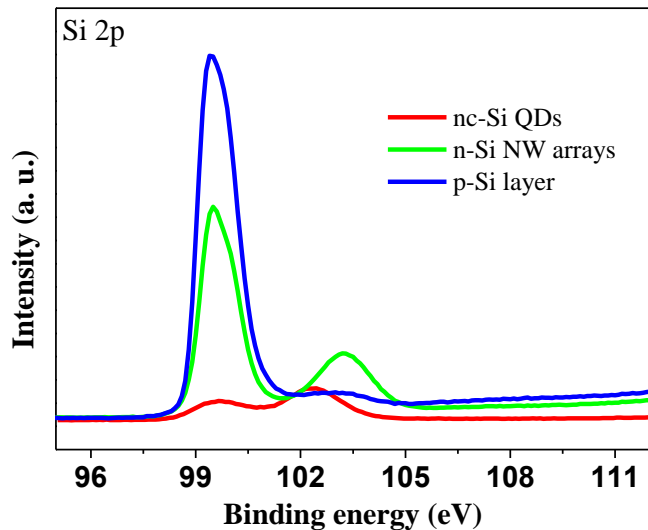


Enhancement in conversion efficiency in presence of nc-Si QDs



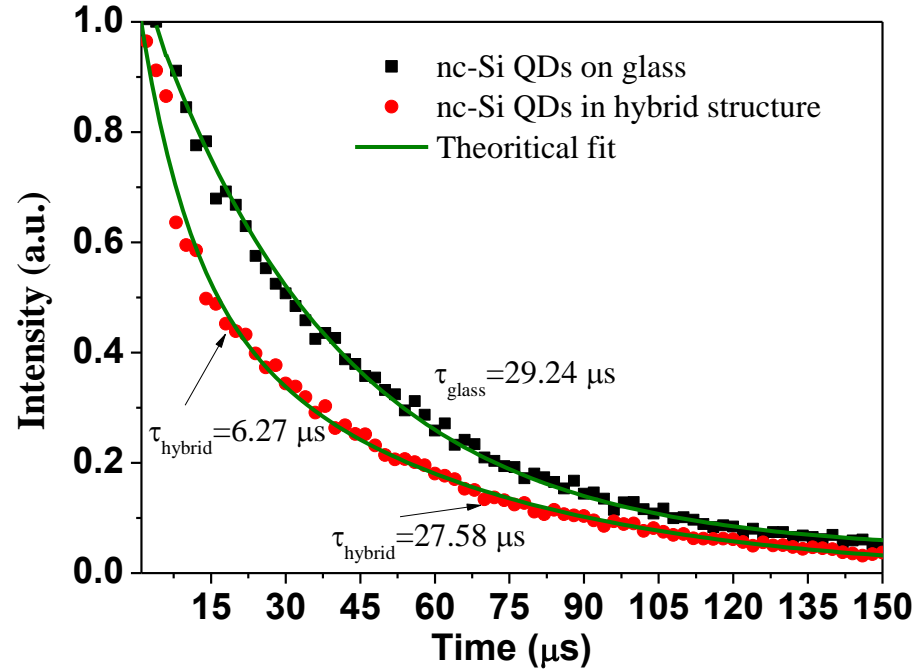
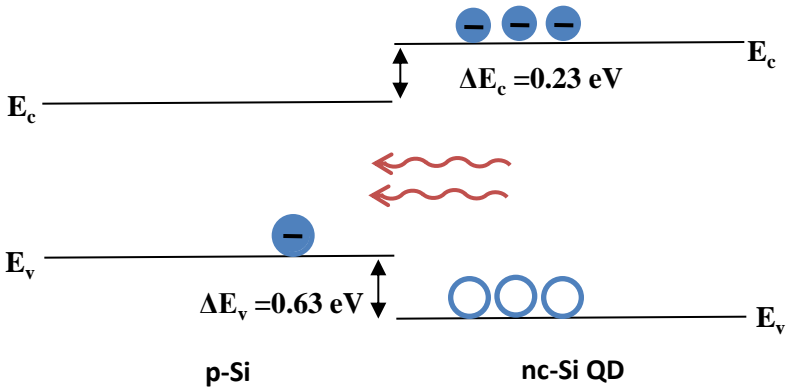
sample	V_{oc} (V)	J_{sc} (mA/cm^2)	FF	η (%)	R_s (Ω/cm^2)	R_{sh} (Ω/cm^2)
nc-Si QD modified hybrid cell	0.47	38.70	0.71	12.9	0.34	7059.2
Without QD modified cell	0.47	32.67	0.71	10.9	0.38	4882.7

X-ray photoelectron spectroscopic observations



Band alignment at the interface of p-Si layer and nc-Si QDs.

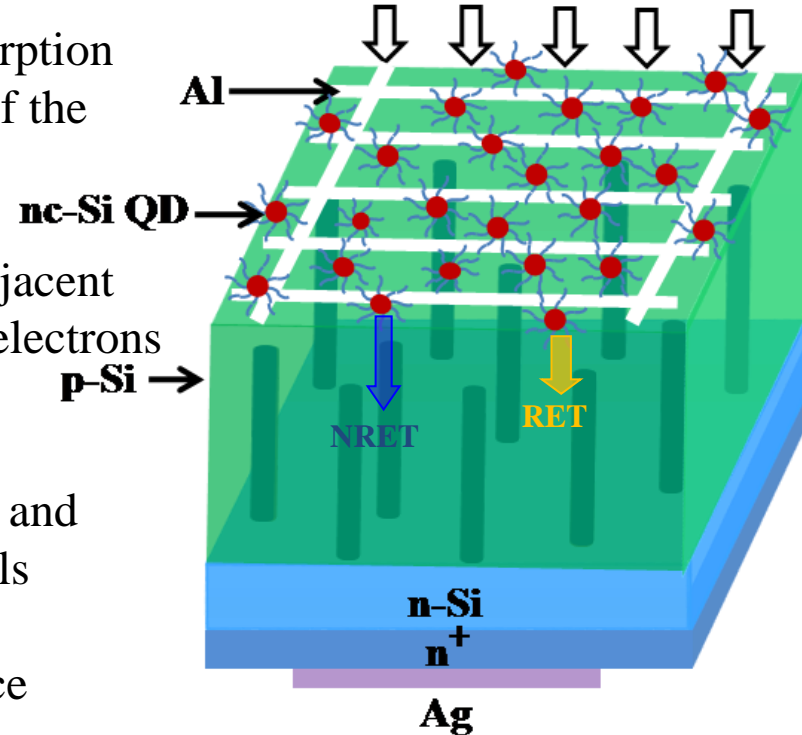
Energy transfer from nc-Si QDs to Si layer



- $\tau_{\text{RET}} \sim (20.9 \mu\text{s})^{-1}$, $\tau_{\text{NRET}} \sim (12.9 \mu\text{s})^{-1}$
- Non radiative energy transfer rate is ~ 1.6 times faster than radiative energy transfer rate

Advantages of ET mediated solar cell architecture

1. Reduction of spectrum loss by greater solar light absorption cross section due to the absorption of the UV region of the solar spectrum by using nc-Si QDs.
2. Resonant excitation transfer from nc-Si QDs to the adjacent Si layer accompanied by the spontaneous creation of electrons and holes.
3. Efficient electron and hole separation in p-n junctions and transport in oppositely doped high mobility Si channels
4. Very low series resistance due to low contact resistance as a result of continuous front contact fabrication.



□ This architecture free from the bottleneck of exciton separation and transport in excitonic solar cells

Acknowledgement

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Thank you!

